Diode Semiconductor Device - Page 1 of 1



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Glass	ure Material:
	U Longth.
	ll Length:
0.200 i	
	nal Length:
1.000 i	
	II Diameter:
0.090 i	
	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-204	
	ing Method:
Termin	
Semic	onductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
4.3 re	egulator voltage
Voltag	e Tolerance In Percent:
-5.0 to	5.0
Currer	nt Rating Per Characteristic:
50.00 r	milliamperes all primaries horsepower metric and 65.00 milliamperes repetitive peak forward current
Power	Rating Per Characteristic:
250.0 r	milliwatts small-signal input power, common-collector absolute
Maxim	um Operating Tempurature Per Measurement Point:
175.0 c	degrees celsius junction
Termir	nal Type And Quantity:
2 unins	sulated wire lead
Shelf L	_ife:
N/a	
Unit O	f Measure:
Demili	tarization:
No	
Fiig:	
-	0